## TANCERAM® CHIP CAPACITORS WAS



TANCERAM® chip capacitors can replace tantalum capacitors in many applications and offer several key advantages over traditional tantalums. Because TANCERAM® capacitors exhibit extremely low ESR, equivalent circuit performance can often be achieved using considerably lower capacitance values. Low DC leakage reduces current drain, extending the battery life of portable products. TANCERAM® high DC breakdown voltage ratings offer improved reliability and eliminate large voltage de-rating common when designing with tantalums.

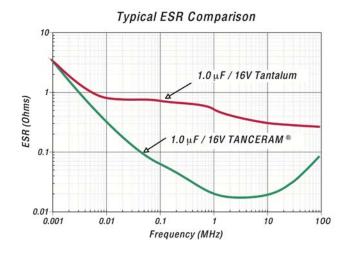
### **ADVANTAGES**

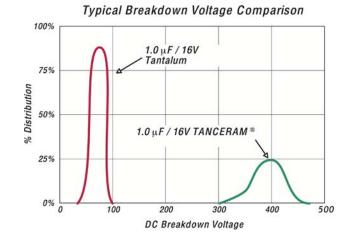
Low ESR

- Low DC Leakage
- Higher Surge Voltage
- Non-polarized Devices
- Reduced CHIP Size
- Improved Reliability
- Higher Insulation Resistance
   Higher Ripple Current

### **APPLICATIONS**

- Switching Power Supply Smoothing (Input/Output)
- DC/DC Converter Smoothing (Input/Output)
- · Backlighting Inverters
- · General Digital Circuits





#### How to Order TANCERAM®

100 VOLTAGE

6R3 = 6.3 V 100 = 10 V 160 = 16 V 250 = 25 V

500 = 50 V

101 = 100 V

R15

SIZE See Chart X

**DIELECTRIC** W = X7RX = X5R

1st two digits are significant; third digit denotes number of

106

CAPACITANCE

zeros. 105 = 1.00 µF  $476 = 47.0 \,\mu\text{F}$  $107 = 100 \,\mu\text{F}$ 

M

**TOLERANCE** 

 $K = \pm 10\%$  $M = \pm 20\%$  **TERMINATION** V = Nickel Barrier

٧

with 100% Tin Plating (Matte)  $T = SnPb^*$ 

(\*available on select parts)

4

Part number written: 100R15X106MV4E

MARKING

4 = Unmarked

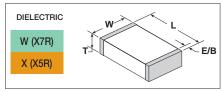
Code Type Reel Plastic Paper Tape specifications conform to EIA RS481

Ε

**PACKING** 



# TANCERAM® CHIP CAPACITORS ROHS



## CASE SIZE

## **CAPACITANCE SELECTION**

EIA / JDI		INCHES	(mm)	VDC	1.0	μF	2.2 μF		3.3 µF		4.7 μF		10 μF		22 μF		47 μF		100 μF		
					10	)5	22	25	335		475		10	06 2		226		476		107	
<b>-</b> 0402	L W T	.040 ±.004 .020 ±.004 .025 Max.	(1.02 ±.10) (0.51 ±.10) (0.64)	16 10																	
R07	EB	.008 ±.004	(0.20±.10)	6.3																	
0000	L	V .032 ±.008 r .035 Max.	(1.60 ±.20) (0.81 ±.20) (0.89) (.25±.13)	25																<u> </u>	
	W			16 10																	
K14	R14			6.3																	
■ 0805 W		L .080 ±.010 W .050 ±.010 T .060 Max. EB .020±.010	(2.03 ±.25) (1.27 ±.25) (1.52) (0.51±.25)	50																	
				25																	
R15				16																<u> </u>	
1113	EB			10																	
				6.3 50																	
_ 1206 w		<b>W</b> .062 ±.010	(3.17 ±.35) (1.57 ±.25) (1.78) (0.51+.3825)	35																	
				25																	
R18	T			16																	
	EB			10																	
-				6.3																	
		<b>L</b> .126 ±.016	(3.20 ±.40)	100																<u> </u>	
	L			50																ļ	
1210 S41	<b>W</b> .098 ±.012	(2.50 ±.30)	35 25											_							
	T	T .110 Max. EB .020 +.015010	(2.8) (0.51+.3825)	16																	
	EB			10																	
				6.3																	
1010	L	<b>W</b> .126 ±.015	(4.50 ±.40) (3.20 ±.38) (3.55)	100																	
1812	W			50																	
S43	EB	.035 ±.020	(0.89 ±0.51)	25																	
					W	Χ	W	Χ	W	Χ	W	Χ	W	Χ	W	Χ	W	Χ	W	Χ	
					"K" OR "M" TOLERANCE						ONLY "M" TOLERANCE										

## **ELECTRICAL CHARACTERISTICS**

DIELECTRIC:	X7R	X5R					
TEMPERATURE COEFFICIENT:	±15% (-55 to +125°C)	±15% (-55 to +85°C)					
DISSIPATION FACTOR:	For $\geq$ 50 VDC: 5% max. For $\leq$ 35 VDC: 10% max.	For ≥ 50 VDC: 5% max. For ≤ 35 VDC: 10% max.					
INSULATION RESISTANCE (MIN. @ 25°C, WVDC)	100 $\Omega F$ or 10 $G\Omega$ , whichever is less						
DIELECTRIC STRENGTH:	2.5 X WVDC, 25°C, 50mA max.						
TEST CONDITIONS:	Capacitance values $\leq$ 10 µF: 1.0kHz±50Hz @ 1.0±0.2 Vrms Capacitance values $>$ 10 µF: 120Hz±10Hz @ 0.5V±0.1 Vrms						
OTHER:	See page 79 for additional dielectric specifications.						

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NMC0402X7R153K16TRPF NMC0603NPO330G50TRPF NMC0603NPO331F50TRPF NMC0603X5R475M6.3TRPF

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C1608X7R1E334K C2012C0G2A472J 2220J2K00562KXT KHC201E225M76N0T00 1812J2K00332KXT CCR06CG153FSV

CDR14BP471CJUR CDR31BX103AKWR CDR33BX683AKUS CGA2B2C0G1H010C CGA2B2C0G1H040C CGA2B2C0G1H050C

CGA2B2C0G1H060D CGA2B2C0G1H070D CGA2B2C0G1H120J CGA2B2C0G1H151J CGA2B2C0G1H1R5C CGA2B2C0G1H2R2C

CGA2B2C0G1H390J CGA2B2C0G1H391J CGA2B2C0G1H3R3C CGA2B2C0G1H680J CGA2B2C0G1H6R8D CGA2B2C0G1H820J